

Docket No.: M4065.0019/P019-A

(PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: Leonard Forbes, et al.

Application No.: 09/750,111

Filed: December 29, 2000

For: HIGH DENSITY SRAM CELL WITH LATCHED VERTICAL TRANSISTORS

Group Art Unit: 2822

Examiner: K. Rose

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AMENDMENT

Box Non-Fee Amendment Commissioner for Patents Washington, DC 20231

Dear Sir:

In response to the Office Action dated February 28, 2003 (Paper No. 9), please amend the above-identified U.S. patent application as follows:

Please see the amendment to the specification, beginning at page 2.

Please see the amendment to the claims, beginning at page 3.

Please consider the following remarks, beginning at page 9.